NSN 5961-00-497-9212



Transistor - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5961-00-497-9212 **Inclosure Material:** Metal **Overall Length:** 0.400 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.437 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 80.0 collector to base voltage, dc and 50.0 collector to emitter voltage, dc and 8.0 emitter to base voltage, instantaneous **Current Rating Per Characteristic:** Between 500.00 milliamperes source cutoff current and 5.00 amperes source cutoff current **Power Rating Per Characteristic:** 30.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 13499-352-0757 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 tab, solder lug Shelf Life: N/a

No

Unit Of Measure:

Demilitarization:

NSN 5961-00-497-9212 Transistor - Page 2 of 2



Fiig:

A110a0